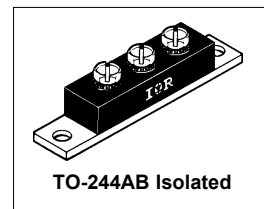


International IRF Rectifier

401CMQ... SERIES

SCHOTTKY RECTIFIER

400 Amp



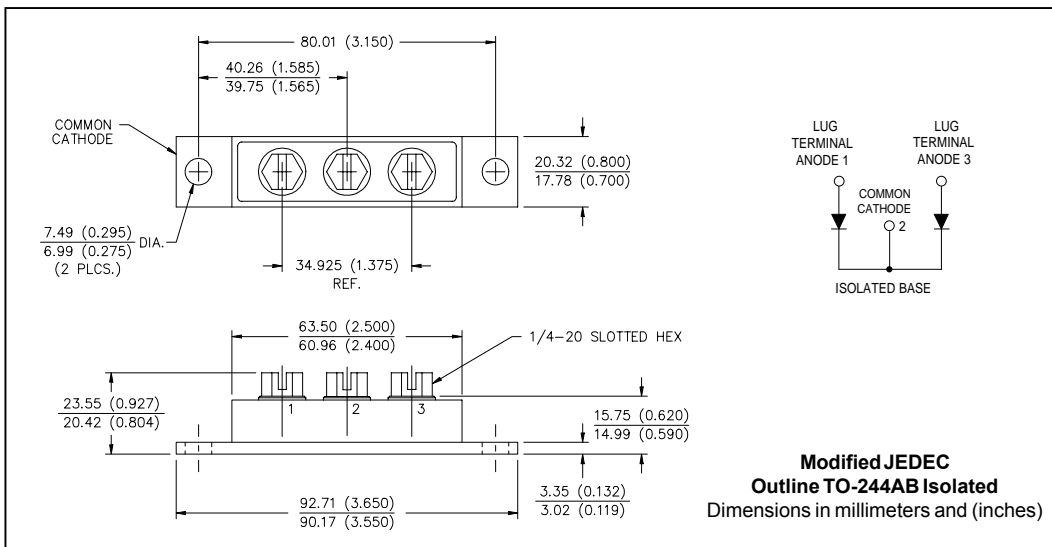
Major Ratings and Characteristics

Characteristics	401CMQ...	Units
$I_{F(AV)}$ Rectangular waveform	400	A
V_{RRM} range	35 to 45	V
I_{FSM} @tp = 5 μ s sine	25,000	A
V_F @200Apk, $T_J = 125^\circ\text{C}$ (per leg)	0.56	V
T_J range	-55 to 175	$^\circ\text{C}$

Description/Features

The 401CMQ center tap, high current, Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 $^\circ\text{C}$ junction temperature. Typical applications are in high current switching power supplies, converters, free-wheeling diodes, welding and reverse battery protection.

- 175 $^\circ\text{C}$ T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Voltage Ratings

Partnumber	401CMQ035	401CMQ040	401CMQ045
V_R Max. DC Reverse Voltage (V)	35	40	45
V_{RWM} Max. Working Peak Reverse Voltage (V)			

Absolute Maximum Ratings

Parameters	401CMQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current (Per Leg) * See Fig. 5 (Per Device)	200 400	A	50% duty cycle @ $T_C = 116^\circ\text{C}$, rectangular waveform
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current (Per Leg) * See Fig. 7	25,000 3450	A	5 μs Sine or 3 μs Rect. pulse 10ms Sine or 6ms Rect. pulse Following any rated load condition and with rated V_{RWM} applied
E_{AS} Non-Repetitive Avalanche Energy (Per Leg)	270	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 40$ Amps, $L = 0.34$ mH
I_{AR} Repetitive Avalanche Current (Per Leg)	40	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J , max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	401CMQ	Units	Conditions
V_{FM} Max. Forward Voltage Drop (Per Leg) * See Fig. 1 (1)	0.67	V	@ 200A $T_J = 25^\circ\text{C}$
	0.78	V	@ 400A
	0.56	V	@ 200A $T_J = 125^\circ\text{C}$
	0.68	V	@ 400A
I_{RM} Max. Reverse Leakage Current (Per Leg) * See Fig. 2 (1)	20	mA	$T_J = 25^\circ\text{C}$ $V_R = \text{rated } V_R$
	180	mA	$T_J = 125^\circ\text{C}$
C_T Max. Junction Capacitance (Per Leg)	10,300	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance (Per Leg)	5.0	nH	From top of terminal hole to mounting plane
dv/dt Max. Voltage Rate of Change	10000	V/ μs	(Rated V_R)
V_{RMS} Insulation Voltage	1000	V	

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	401CMQ	Units	Conditions
T_J Max. Junction Temperature Range	-55 to 175	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-55 to 175	$^\circ\text{C}$	
R_{thJC} Max. Thermal Resistance Junction to Case (Per Leg)	0.4	$^\circ\text{C}/\text{W}$	DC operation * See Fig. 4
R_{thJC} Max. Thermal Resistance Junction to Case (Per Package)	0.2	$^\circ\text{C}/\text{W}$	DC operation
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.1	$^\circ\text{C}/\text{W}$	Mounting surface, smooth and greased
wt Approximate Weight	79 (2.80)	g (oz.)	
T Mounting Torque	Base	Min.	24 (20)
		Max.	35 (30)
	Center Hole	Typ.	13.5 (12)
	Terminal Torque	Min.	35 (30)
		Max.	46 (40)
Case Style	TO-244AB isolated		Modified JEDEC

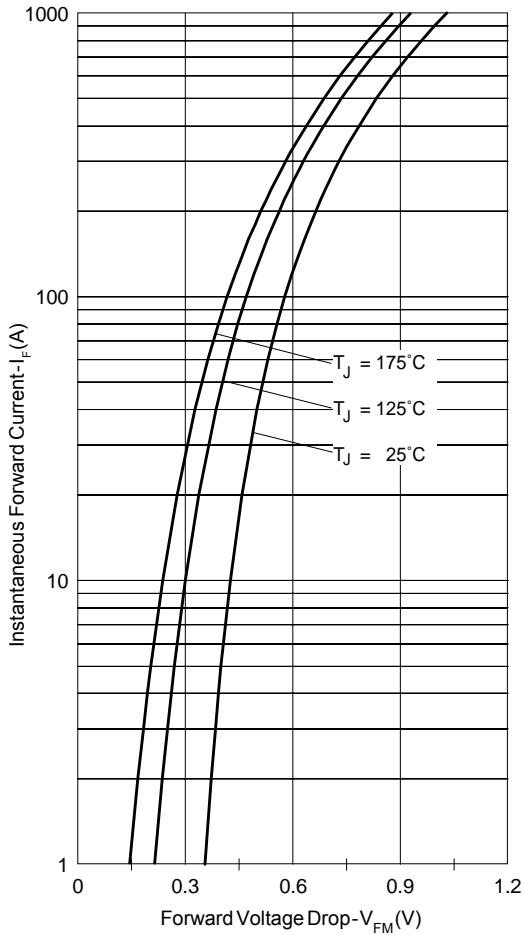


Fig. 1 - Max. Forward Voltage Drop Characteristics

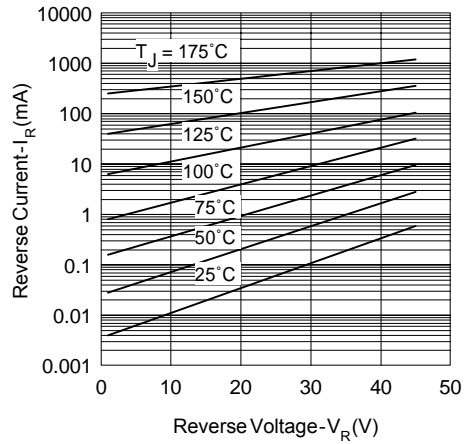


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

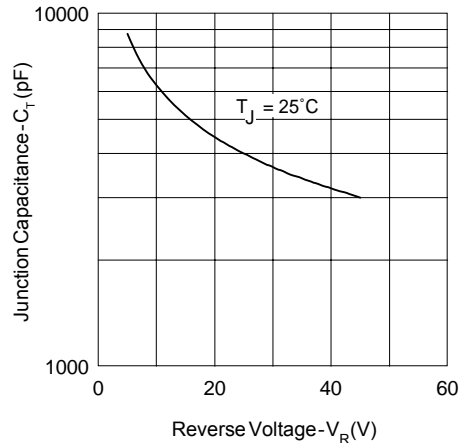


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

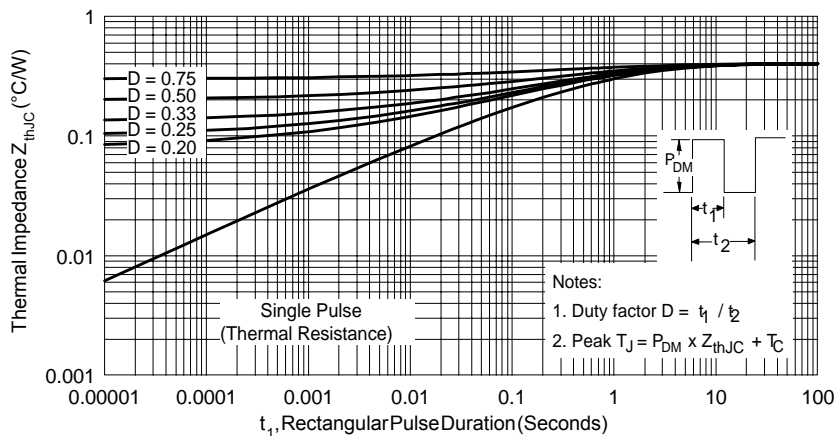


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (Per Leg)

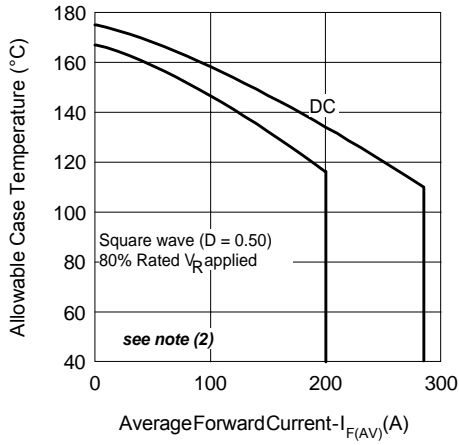


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

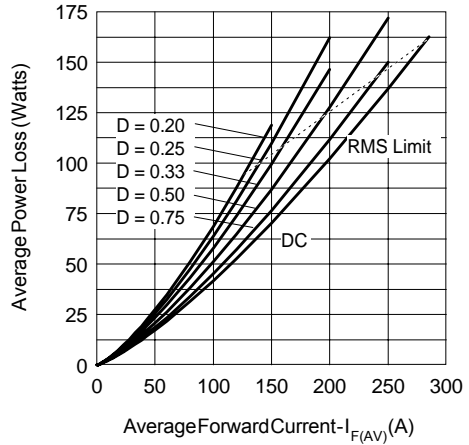


Fig. 6 - Forward Power Loss Characteristics

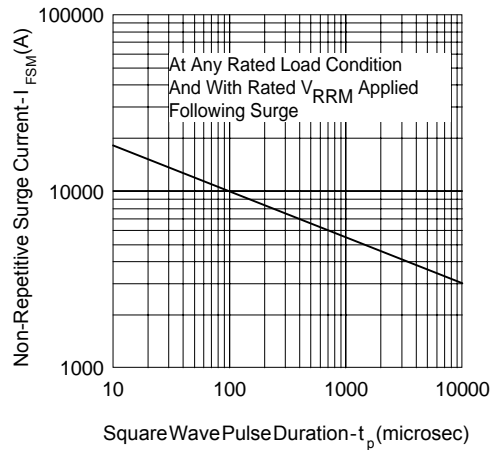


Fig. 7 - Max. Non-Repetitive Surge Current

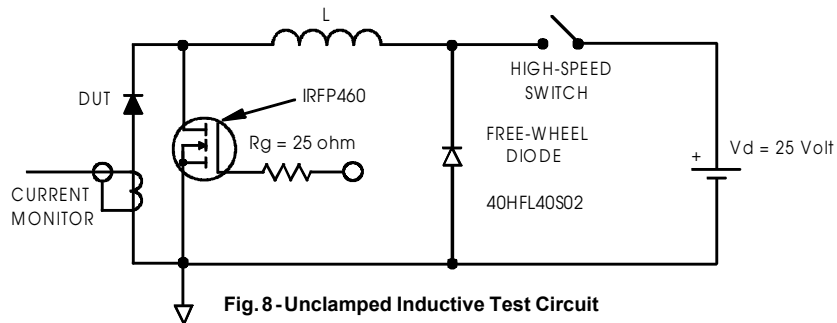


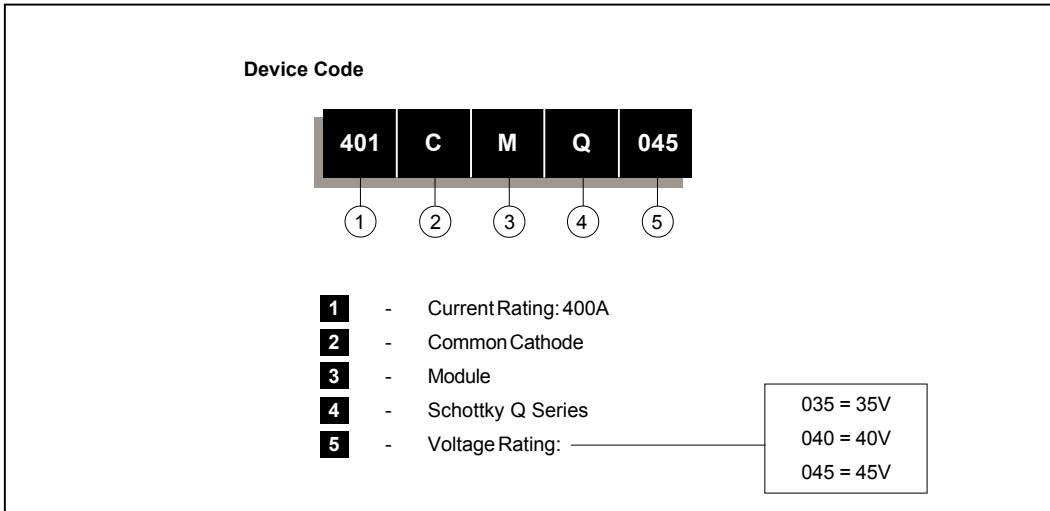
Fig. 8 - Unclamped Inductive Test Circuit

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\%$ rated V_R

Ordering Information Table



Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.



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